1. Record Nr. UNINA9910346840003321 Autore Verd Jaume Titolo Development of CMOS-MEMS/NEMS Devices / Jaume Verd, Jaume Segura MDPI - Multidisciplinary Digital Publishing Institute, 2019 Pubbl/distr/stampa Basel, Switzerland:,: MDPI,, 2019 **ISBN** 9783039210695 3039210696 Descrizione fisica 1 electronic resource (165 p.) Soggetti History of engineering and technology Lingua di pubblicazione Inglese **Formato** Materiale a stampa Livello bibliografico Monografia Sommario/riassunto Micro and nano-electro-mechanical system (M/NEMS) devices constitute key technological building blocks to enable increased additional functionalities within Integrated Circuits (ICs) in the More-Than-Moore era, as described in the International Technology Roadmap for Semiconductors. The CMOS ICs and M/NEMS dies can be combined in the same package (SiP), or integrated within a single chip (SoC). In the SoC approach the M/NEMS devices are monolithically integrated together with CMOS circuitry allowing the development of compact and low-cost CMOS-M/NEMS devices for multiple applications (physical sensors, chemical sensors, biosensors, actuators, energy actuators, filters, mechanical relays, and others). On-chip CMOS electronics integration can overcome limitations related to the extremely low-level signals in sub-micrometer and nanometer scale electromechanical transducers enabling novel breakthrough applications. This Special Issue aims to gather high quality research contributions dealing with MEMS and NEMS devices monolithically integrated with CMOS,

independently of the final application and fabrication approach adopted

(MEMS-first, interleaved MEMS, MEMS-last or others).]